IES-2012- Paper-I

(A) 1 and 4 only

(C) 2 and 3 only

	 -					
1.	The I-V character	istics of a tunnel diode ex	hibit			
	(A) current-contro	olled negative resistance				
		olled negative resistance				
	(C) temperature-c	ontrolled positive resistan	ice			
	(D) current-contro	olled positive resistance				
2.	A gate to drain-co	nnected enhancement mo	de MOSFET is an exam	nple of		
	(A) an active load		(B) a switching de	evice		
	(C) a three-termin	al device	(D) a three-termin	al device		
3.	Thermal runway i	Thermal runway is not possible in FET because, as the temperature of FET increases				
	(A) the drain current increases		(B) the mobility in	ncreases		
	(C) the mobility d	ecreases	(D) the transcondu	actance increases		
4.	The output impedance of a BJT under common-collector configuration is					
	(A) Low	(B) High	(C) Medium	(D) Very high		
5.	Consider the follo	Consider the following statements related to JFET:				
	1. Its operation depends on the flow of minority carriers only.					
	2. It is less noisy than BJT					
	3. It has poor thermal stability					
	4. It is relatively immune to radiation					
	The correct statements are					
	(A) 1, 2, 3 and 4		(B) 1 and 2 only			
	(C) 2 and 4 only		(D) 3 and 4 only			
6.	For common-collector amplifier, the current gain (A _I) is					
	(A) $1+h_{fe}$	(B) $\frac{1 + h_{fe}}{1 + h_{oe} R_L}$	(C) $\frac{1 + h_{fe}}{h_{oe} h_{ie}}$	(D) $\frac{1 + h_{fe}}{1 + h_{ie}R_L}$		
7.	Consider the follo	wing statements:				
	(1) Speed of operation of MOSFET is more than the speed of operation of SCR					
	(2) SCRs have lower power loss than MOSFETs.					
	(3) The current in conducting state can easily be controlled through the gate in SCR.					
	(4) MOSFET is not a current triggered device.					
	The correct staten					

(B) 1 and 2 only

(D) 1,2,3 and 4



8. Match List-I with List-II and select the correct answer using the code given below the

List – I	List – II
P. di / dt rating limits	1. Snubber circuit
Q. dv / dt rating	2. Heat sink
R. i ² t limit	3. Series reactor
S. Junction temperature limit	4. Fuse

Codes:

P Q R S

- (A) 2 4 1 3
- (B) 2 1 4 3
- (C) 3 4 1 2
- (D) 3 1 4 2
- 9. An SCR can be turned off
 - (A) by passing a negative pulse to its gate
 - (B) by removing the gate supply
 - (C) by reverse biasing it
 - (D) by forcing the current through gate to become zero
- 10. Body effect in MOSFETs results in
 - (A) increase in the value of transconductance
 - (B) change in the value of threshold voltage
 - (C) decrease in the value of transconductance
 - (D) increase in the value of output resistance
- 11. The efficiency of an LED for generating light is directly proportional to the
 - (A) applied voltage

(B) current injected

(C) temperature

(D) level of doping

12. A signal f(t) is described as

$$f(t) = [1-|t|] \text{ when } |t| \le 1$$
$$= 0 \text{ when } |t| > 1$$

The represents the unit

(A) sinc function

(B) area triangular function

(C) signum function

(D) parabolic function



13. Match List – I with List – II and select the correct answer using the code given below the Lists:

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List – I	List – II	
(P) Even signal	$(1) x(n) = \left(\frac{1}{4}\right)^n u(n)$	
(Q) Causal signal	(2) x(-n) = x(n)	
(R) Periodic signal	(3) x(t)u(t)	
(S) Energy signal	(4) x(n) = x(n+N)	

Codes:

- (A) 2 3 4 1
- (B)
- (C) 1 3 4 2
- (D) 1 4 3 2

14. The period of the signal $x(t) = 10\sin 12\pi t + 4\cos 18\pi t$ is

- (A) $\frac{\pi}{4}$
- (B) $\frac{1}{6}$
- (C) $\frac{1}{9}$
- (D) $\frac{1}{3}$

A linear time-invariant system has an impulse response of e^{2t} , t > 0. If the initial conditions 15. are zero and the input is e^{3t} , the output for t > 0 is

- (A) $e^{3t} e^{2t}$
- (B) e^{5t}
- (C) $e^{3t} + e^{2t}$
- $(D) e^{t}$

A system described by the following differential equation is initially at rest and then excited 16. by the input x(t) = 3 u(t):

$$\frac{d^2y}{dt^2} + 4\frac{dy}{dt} + 3y = x(t).$$
 The output y(t) is

(A) $1-1.5e^{-t} + 0.5e^{-3t}$

(B) $1 - 0.5e^{-t} + 1.5e^{-3t}$

(C) $1+1.5e^{-t}-0.5e^{-3t}$

(D) $1+0.5e^{-t}+0.5e^{-3t}$

17. The natural response of an LTI system described by the difference equation

$$y(n) - 1.5y(n-1) + 0.5y(n-2) = x(n)$$
 is

- (A) $y(n) = 0.5u(n) 2(0.5)^n u(n)$
- (B) $y(n) = 0.5u(n) (0.5)^n u(n)$
- (C) $y(n) = 2u(n) 0.5(0.5)^n u(n)$
- (D) $y(n) = 2u(n) (0.5)^n u(n)$



18. Consider a system described by the state model

$$\mathbf{x} = \begin{bmatrix} 2 & 1 \\ -1 & 2 \end{bmatrix} \mathbf{x} + \begin{bmatrix} 1 \\ 1 \end{bmatrix} \mathbf{U}$$
$$\mathbf{Y} = \begin{bmatrix} 1 & 1 \end{bmatrix} \mathbf{X}$$

The system is

- (A) controllable but not observable
- (B) uncontrollable and observable
- (C) both controllable and observable
- (D) neither controllable nor observable
- 19. The system represented by the state-variable model

$$\mathbf{x} = \begin{bmatrix} 0 & -1 \\ 1 & -2 \end{bmatrix} \mathbf{x} + \begin{bmatrix} 1 \\ 2 \end{bmatrix} \mathbf{U} \text{ is}$$

(A) oscillatory

(B) critically damped

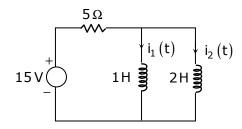
(C) over-damped

- (D) under-damped
- 20. A second-order system represented by state variables has

$$\mathbf{x} = \begin{bmatrix} -2 & -4 \\ 1 & 0 \end{bmatrix}$$

The values of natural frequency and damping factor are respectively

- (A) 2 and 0.5
- (B) 2 and 1
- (C) 1 and 2
- (D) 0.5 and 2
- 21. The steady-state value of the currents $i_1(t)$ and $i_2(t)$ in the circuit are

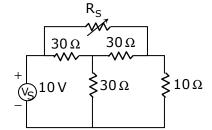


(A) 2A and 1A

(B) 1.5 A and 1.5 A

(C) 1A and 2A

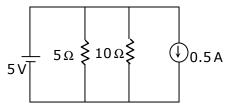
- (D) 1 A and 1 A
- In the circuit, the value of the resistance R_S required for maximum power transfer from the 10V source to the 10Ω load is given by
 - (A) 5Ω
 - (B) 10Ω
 - (C) 0Ω
 - (D) 30Ω



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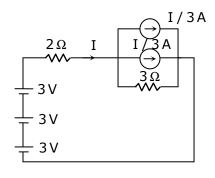


23. The total resistance faced by the voltage source having zero internal resistance in the circuit is

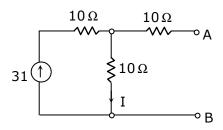


- (A) 10Ω
- $(B) 5\Omega$
- $(C) 2.5 \Omega$
- (D) 1.5Ω

24. In the circuit, the voltage across 3Ω resistance is



- (A) 1 V
- (B) 3 V
- (C) 6 V
- (D) 9 V
- 25. In the circuit shown, Thevenin's voltage as seen from the terminals AB is



(A) 0 V

(B) 1.5 V

(C) 6.0 V

- (D) indeterminate
- 26. A random variable is known to have a cumulative distribution function

$$F_x(x) = U(x)\left(1 - \frac{x^2}{b}\right)$$
 its density function is

(A) $U(x)\frac{2x}{b}(1-e^{-x^2/b})$

(B) $U(x)\frac{2x}{b}e^{-x^2/b}$

(C) $U(x)\left(1-\frac{x^2}{b}\right)\delta(x)$

(D) $\left(1-\frac{x^2}{b}\right)\delta(x)+e^{-x^2/b}$

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- 27. The probability cumulative distribution function must be monotone and
 - (A) Increasing

(B) decreasing

(C) Non-increasing

- (D) non-decreasing
- 28. The step response of a discrete time system with transfer function $H(Z) = \frac{10}{(Z-1)(Z+2)}$ is given by
 - (A) $\frac{-10}{9} + \frac{10}{3}n + \frac{10}{9}(-2)^n$

(B) $-5 + \frac{n}{2} + (-2)^n$

(C) $\frac{-7}{9} + \frac{5}{3}n + (-3)^n$

- (D) $-2 + 5(1-2^n)$
- 29. The Z-transform corresponding to the Laplace transform function
 - $G(s) = \frac{10}{s(s+5)}$ is
 - (A) $\frac{2Ze^{-5z}}{(Z-1)(Z-e^{-T})}$

(B) $\frac{2(1-e^{-5z})Z}{(Z-1)(Z-e^{-5T})}$

(C) $\frac{e^{-5T}}{(Z-1)^2}$

- (D) $\frac{e^{-T}}{Z(Z-e^{-3T})}$
- 30. The difference equation for a system is given by

$$y(n+2)+y(n+1)+0.16y(n)=x(n+1)+0.32x(n)$$

The transfer function of the system is

(A)
$$\frac{Z+0.32}{Z^2+Z+0.16}$$

(B)
$$\frac{1}{Z^2 + Z + 0.16}$$

(C)
$$\frac{Z+0.32}{Z^2+0.16}$$

(D)
$$\frac{Z+0.32}{(Z-1)(Z^2+Z+0.16)}$$

- 31. The discrete time system described by $y(n) = x(n)^2$ is
 - (A) Causal and linear

(B) causal and non-linear

(C) Non-causal and linear

- (D) non-causal and non-linear
- 32. The impulse response of a discrete time system is given by

$$h(n) = \frac{1}{2} (\delta[n] + \delta[n-2])$$

The magnitude of the response can be expressed as

- (A) $|\cos \Omega|$
- (B) $\cos \Omega$
- (C) $|\sin \Omega|$
- (D) $\sin \Omega$



- 33. $H(e^{j\omega})$ is the frequency response of a discrete time LTI system and $H_1(e^{j\omega})$ is the frequency response of its inverse function. Then
 - (A) $H(e^{j\omega})H_1(e^{j\omega})=1$

(B) $H(e^{j\omega})H_1(e^{j\omega}) = \delta(\omega)$

(C) $H(e^{j\omega})*H_1(e^{j\omega})=1$

- (D) $H(e^{j\omega})*H_1(e^{j\omega})=\delta(\omega)$
- 34. With the following equations, the time-invariant systems are
 - (1) $\frac{d^2y(t)}{dt^2} + 2t\frac{d}{dt}y(t) + 5y(t) = x(t)$
 - (2) $y(t) = e^{-2x(t)}$
 - (3) $y(t) = \left[\frac{d}{dt} x(t)\right]^2$
 - (4) $y(t) = \frac{d}{dt} \left[e^{-2t} x(t) \right]$
 - (A) 1 and 2
- (B) 1 and 4
- (C) 2 and 3
- (D) 3 and 4
- 35. If F(s) and G(s) are the Laplace transforms of f(t) and g(t), then their product F(s). G(s) = H(s), where H(s) is the Laplace transform of h(t), is defined as
 - (A) (f.g)(t)

- (B) $\int_0^t f(\tau)g(t-\tau)dg\tau$
- (C) Both (a) and (b) are correct
- (D) f(t).g(t)
- 36. Consider a system with transfer function

$$H(s) = \frac{3s^2 - 2}{s^2 + 3s + 2}$$

The step response of the system is given by

- (A) $C(t) = (5e^{-2t} e^{-t} 1)u(t)$
- (B) $C(t) = 3\delta(t) 10e^{-2t}u(t) + e^{-t}u(t)$
- (C) $C(t) = (4e^{-t} e^{-2t} 1)u(t)$
- (D) $C(t) = 2(1 e^{-2t})u(t)$
- 37. The Fourier transform of a rectangular pulse is
 - (A) another rectangular pulse

(B) triangular pulse

(C) sinc function

- (D) impulse function
- 38. The function which has its Fourier transform, Laplace transform and Z-transform unity is
 - (A) Gaussian
- (B) impulse
- (C) sinc
- (D) pulse

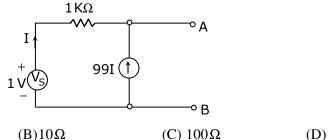


- 39. The property of Fourier transforms which states that the compression in time domain is equivalent to expansion in the frequency domain is
 - (A) duality

(B) scaling

(C) time scaling

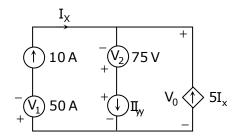
- (D) frequency shifting
- 40. A waveform is given by $v(t) = 10\sin 2\pi 100t$. What will be the magnitude of the second harmonic in its Fourier series representation?
 - (A) 0 V
- (B) 20 V
- (C) 100 V
- (D) 200 V
- 41. Thevenin's equivalent resistance as seen from the terminals AB for the circuit is



(A) $1k\Omega$

(D) $10k\Omega$

42. The total power developed in the circuit, if $V_0 = 125 \text{ V}$ is



(A) 0 watt

(B) 4000 watts

(C) 8000 watts

- (D) 16000 watts
- 43. In the circuit given, the switch is closed at t = 0+. The initial voltages on the capacitors are indicated in the diagram. The voltages $V_{cl}(t)$ and $V_{c2}(t)$ for $t \ge 0$ are respectively

$$V_{c1}\left(t\right) = 0$$

$$V_{c1}\left(t\right) = 0.5\mu F$$

$$V_{c2}\left(t\right) = 0.5\mu F$$

$$V_{c2}\left(t\right) = 0.5\mu F$$

$$V_{c1}\left(0-\right) = 1V$$

$$V_{c2}\left(0-\right) = 1V$$

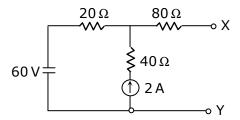
(A)
$$\frac{1}{2} (1 - e^{-t})$$
 and $\frac{1}{2} (1 + e^{-t})$

(B)
$$(1 - e^{-t})$$
 and $\frac{1}{2}(1 + e^{-t})$

(C)
$$\frac{1}{2} (1 + e^{-t})$$
 and $\frac{1}{2} (1 + e^{-t})$

(D)
$$\frac{1}{2} \left(1 + e^{-t} \right)$$
 and $\frac{1}{2} \left(1 + e^{-t/2} \right)$

44. In the circuit, Thevenin's voltage and resistance across the terminals XY will be



(A) 20 V and 100Ω

(B) 40 V and 93.33 Ω

(C) 60 V and 93.33Ω

- (D) 100 V and 100Ω
- 45. A voltage of 24 V DC is applied through switch S to an R-L series circuit. Switch S was initially open. At time t = 0, switch is closed. The rate of change of current through the resistor is 8 A/s, while the current through the inductor is 8 A. If the value of the inductor is 1 H, then for this condition the value of the resistor will be
 - (A) 1Ω
- (B) 2Ω
- (C) 3Ω
- (D) 4Ω
- The steady-state response of a network to the excitation $V\cos(\omega t + \phi)$ may be found in three 46. steps. The fist two steps are as follows:
 - 1. Determining the response of the network to the excitation $e^{j\omega t}$
 - 2. Multiplying the above response by $\overline{V} = Ve^{j\phi}$

The third step is

- (A) finding the complex conjugate of the expression after step 2
- (B) finding the magnitude of the expression after step 2
- (C) finding the real part of the expression after step 2
- (D) finding the imaginary part of the expression after step 2
- 47. The unit step response y(t) of a linear system is

$$y(t) = (1-3e^{-t} + 3e^{-2t})u(t)$$

For the system function, the frequency at which the forced response become zero is

(A)
$$\frac{1}{\sqrt{2}}$$
 rad/s (B) $\frac{1}{2}$ rad/s (C) $\sqrt{2}$ rad/s

(B)
$$\frac{1}{2}$$
 rad / s

(C)
$$\sqrt{2}$$
 rad / s



48. For a given connected network and for a fixed tree, the fundamental loop matrix is given by

$$\mathbf{B} = \begin{bmatrix} 1 & 0 & 0 & 1 & 0 & 0 \\ 0 & 1 & 0 & 0 & 0 & -1 \\ 0 & 0 & 1 & 1 & -1 & -1 \end{bmatrix}$$

The fundamental cut-set matrix Q corresponding to the same tree is given by

(B)
$$Q = \begin{bmatrix} -1 & 0 & 1 & 1 & 0 & 0 \\ 0 & 0 & -1 & 0 & 1 & 0 \\ 0 & 1 & 1 & 0 & 0 & 1 \end{bmatrix}$$

(C)
$$Q = \begin{bmatrix} 1 & 0 & 1 & 1 & 0 & 0 \\ 0 & 0 & -1 & 0 & 1 & 0 \\ 0 & 1 & 1 & 0 & 0 & 1 \end{bmatrix}$$

(D)
$$Q = \begin{bmatrix} 0 & 0 & 0 & 1 & 0 & 0 \\ 0 & 1 & 0 & 0 & 0 & -1 \\ 1 & 0 & 1 & 1 & -1 & -1 \end{bmatrix}$$

49. For a two-port network, V_1 and V_2 given by

$$V_1 = 60I_1 + 20I_2$$
$$V_2 = 20I_1 + 40I_2$$

The Y-parameters of the network are

$$Y_{11} = 20 \times 10^{-3}$$
(A)
$$Y_{12} = -10 \times 10^{-3}$$

$$Y_{21} = -10 \times 10^{-3}$$

$$Y_{22} = 30 \times 10^{-3}$$

$$Y_{11} = -10 \times 10^{-3}$$
(B)
$$Y_{12} = 20 \times 10^{-3}$$

$$Y_{21} = 20 \times 10^{-3}$$

$$Y_{22} = -30 \times 10^{-3}$$

$$Y_{11} = 10 \times 10^{-3}$$
(C)
$$Y_{12} = -20 \times 10^{-3}$$

$$Y_{21} = -20 \times 10^{-3}$$

$$Y_{22} = 30 \times 10^{-3}$$

$$Y_{11} = -20 \times 10^{-3}$$
(D)
$$Y_{12} = 10 \times 10^{-3}$$

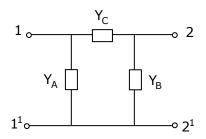
$$Y_{21} = 10 \times 10^{-3}$$

$$Y_{22} = -30 \times 10^{-3}$$

- 50. The h_{11} and h_{22} of a standard T-network with series impedance 2Ω and 7Ω , and shut branch impedance of 3Ω are
 - (A) 5Ω and 10 mho respectively
- (B) 10Ω and 5 mho respectively
- (C) 5Ω and 0.1 mho respectively
- (D) 10Ω and 0.2 mho respectively



51. For the 2-port network shown the parameter Y_{12} is Equal to?



- $(A) Y_C$
- (B) $Y_C + Y_B$
- $(D) -Y_C$
- 52. The Transmission parameter matrix [T] for an ideal Transformer of n₁:n₂ is given by

(A)
$$\begin{bmatrix} \frac{n_1}{n_2} & 1 \\ 0 & \frac{n_2}{n_1} \end{bmatrix}$$

- (A) $\begin{vmatrix} \frac{n_1}{n_2} & 1 \\ 0 & \frac{n_2}{n_2} \end{vmatrix}$ (B) $\begin{vmatrix} \frac{n_1}{n_2} & 0 \\ 0 & \frac{n_2}{n_2} \end{vmatrix}$ (C) $\begin{vmatrix} \frac{n_1}{n_2} & 1 \\ 0 & \frac{-n_2}{n_2} \end{vmatrix}$ (D) $\begin{vmatrix} \frac{n_1}{n_2} & 0 \\ 0 & -\frac{n_2}{n_2} \end{vmatrix}$
- 53. A 2-port network has parameters of ABCD. If all the impedances in the network are Doubled, then
 - (A) A and D are remain un changed B is doubled and C is halved
 - (B) A, B, C and D are all Doubled
 - (C) A and D are doubled C and B remain unchanged
 - (D) A and D remain unchanged C is doubled and B is halved
- 54. The conditions under which a passive 2-port network represented by ABCD if reciprocal and symmetrical are

(A)
$$AD - BC = 1$$
; $A = C$

(B)
$$AD - BC = 0$$
; $A = D$

(C)
$$AD - BC = 1$$
; $D = A$

(D)
$$AD - BC = 0$$
; $C = B$

- 55. The maximum power that a 12 V DC source with an internal resistance of 2Ω can supply to a resistive load is
 - (A) 72 W
- (B) 48 W
- (C) 24 W
- (D) 18 W
- 56. A two-terminal network consists of a coil having inductance L and resistance R shunted by a capacitance C. The poles and zeros of the driving-point impedance function $Z(\omega)$ are located as poles at $-\frac{1}{2} \pm \frac{\sqrt{3}}{2}$ and zero at -I. If Z(0) = 1, the values of R, L and C are
 - (A) 1Ω , 1H and 1μ F

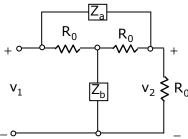
(B) 1Ω , 1H and 1F

(C) 1Ω , 1μ H and 1F

(D) $1k\Omega$, 1H and 1F



57. The condition under which the input impedance at port 1 for the above network will be equal to R_0 is



 $(A) Z_a + Z_b = R_0$

(B) $Z_a Z_b = R_0^2$

(C) $Z_a / Z_b = 1$

- (D) $Z_a / Z_b = \frac{1}{2}$
- 58. If the potential difference between points A(1, 0, 0) and B(2, 0, 0) is 10 V, determine d for point C(d, 0, 0), when V_{BC} is 6 V in a uniform field.
 - (A) 1m
- (B) 2 m
- (C) 6 m
- (D) 5 m
- 59. There are three charges, which are given by $Q_1 = 1\mu C$, $Q_2 = 2\mu C$ and $Q_3 = 3\mu C$. The field due to each charge at a point P in free space is $(a_x + 2a_y a_z)$, $(a_y + 3a_z)$ and $(2a_x a_y)$ newtons /coulomb. The total field at the point P due to all three charges is given by
 - (A) $1.6a_x + 2.2a_y + 2.5a_z$ newtons/coulomb
 - (B) $0.3a_x + 0.2a_y + 0.2a_z$ newtons/coulomb
 - (C) $3a_x + 2a_y + 2a_z$ newtons/coulomb
 - (D) $0.6a_x + 0.2a_y + 0.5a_z$ newtons/coulomb
- 60. The credit of defining the following current is due to Maxwell
 - (A) Conduction current

(B) Drift current

(C) Displacement current

- (D) Diffusion current
- 61. In a digital frequency meter, the Schmitt trigger is used for
 - (A) Converting sinusoidal waveforms into rectangular pulses
 - (B) Scaling of sinusoidal waveforms
 - (C) Providing timebase
 - (D) Triggering a start pulse
- 62. The following transducer(s) may employ strain gauge as a secondary transducer
 - (A) Load cell only
 - (B) Load cell and torquemeter only
 - (C) Load cell, torquemeter and accelerometer only
 - (D) Load cell, torquemeter, accelerometer and flowmeter

63.	A Q-meter is supplied with an oscillator having a 500 mV output voltage. While testing an unknown inductor, the voltage across the variable capacitor of the Q-meter, measured by a digital voltmeter, is obtained as 10 V. The Q-factor of the inductor is				
	(A) 5	(B) 10	(C) 20	(D) 0.05	
64.	Lissajous pattern shown in a double-beam cathode-ray oscilloscope screen for two sinusoidal voltages of equal magnitude and of the same frequency but of phase shift of 30° electrical is (A) a circle (B) a straight line at 45° in the first and third quadrant				
	•	he first and third quadr			
	(D) an ellipse in t	he second and fourth q	uadrant		
65.		A d'Arsonval meter of $100\Omega DC$ coil and 0-1 mA sensitivity gives full-scale reading of 10 A on using an external resistance of			
	(A) 100Ω	(B) 10Ω	(C) 0.01Ω	(D) 0.001Ω	
66.	measuring (A) DC voltage (B) AC voltage (C) Voltage with		nsitivity as compared to d	eflection-type instrument	
67.	The following type of instrument can be used for measuring AC voltage of the highest frequency with reasonable accuracy				
	(A) Electrodynam	ometer	(B) Moving-iron		
	(C) Thermal-therr	noelectric	(D) Rectifier		
68.	To increase the range of a voltmeter (A) A low resistance in series is connected with the voltmeter (B) A low resistance in parallel is connected with the voltmeter (C) A high resistance in series is connected with the voltmeter (D) A high resistance in parallel is connected with the voltmeter				
69.	For the recording of very fast random signals, the most suitable instrument would be				
	(A) Dual-trace		(B) sampling osc	illoscope	
	(c) Real-time spec	etrum analyzer	(D) scanning-type	e spectrum analyzer	



70.	A resistance is measured by a voltmeter-ammeter method using DC excitation and a
	voltmeter of very high resistance connected directly across the unknown resistance. If the
	voltmeter and ammeter are subject to maximum error of $\pm 2.4\%$ and $\pm 1.0\%$ respectively,
	then the magnitude of maximum error in the value of resistance obtained from the
	measurement is nearly

- (A) 1.4%
- (B) 1.7%
- (C) 2.4%
- (D) 3.4%

71. During measurement of voltage and current in a load, ammeter and voltmeter are connected in series and across the load respectively. If ammeter and voltmeter positions are interchanged by mistake, then

- (A) Voltmeter will be damaged
- (B) ammeter will be damaged
- (C) Both the meters will be damaged
- (D) both the meters will be safe

72. The directivity of a $\lambda/2$ long wire antenna is

- (A) 1.5
- (B) 1.66
- (C) 2

(D) $\sqrt{2}$

73. The ratio of the transverse electric field to the transverse magnetic field is called as

(A) Waveguide impedance

(B) waveguide wavelength

(C) Phase velocity

(D) Poynting vector

74. Consider a rectangular waveguide of internal dimensions 8 cm x 4 cm. Assuming an H_{10} mode of propagation, the critical wavelength would be

- (A) 8 cm
- (B) 16 cm
- (C) 4 cm
- (D) 32 cm

75. $n = \sqrt{\left(\frac{m\pi}{a}\right)^2 + \left(\frac{n\pi}{b}\right)^2 - \omega^2 \mu \epsilon}$ represents the propagation constant in a rectangular

waveguide for

(A) TE waves only

(B) TM waves only

(C) TEM waves

(D) TE and TM waves

76. With the symbols having their standard meaning, cut-off frequency (frequency below which wave propagation will not occur) for a rectangular waveguide is

 $(A) \ \frac{1}{\sqrt{\mu\epsilon}} \sqrt{\left(\frac{m\pi}{a}\right) + \left(\frac{n\pi}{b}\right)}$

(B) $\frac{1}{2\pi\sqrt{\mu\epsilon}}\sqrt{\left(\frac{m\pi}{a}\right)^2+\left(\frac{n\pi}{b}\right)^2}$

(C) $\frac{1}{2\pi\sqrt{\mu\epsilon}} \left(\frac{m\pi}{a}\right) + \left(\frac{n\pi}{b}\right)$

(D) $\frac{1}{\sqrt{\mu\epsilon}}\sqrt{\left(\frac{m\pi}{a}\right)^2 + \left(\frac{n\pi}{b}\right)^2}$

77. A plane wave travelling in a medium of $\epsilon_r = 1$, $\mu_r = 1$ (free space) has an electric field intensity of $100\sqrt{\pi}\,V$ / m . Determine the total energy density of this magnetic field.

(A) 13.9 nJ/m^3

(B) 27.8 nJ/m^3

(C) 139 nJ/m^3

(D) 278 nJ/m^3

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78.	A $\lambda/4$ line, shorted at one end, presents impedance at the other end equal to				
	$(A) Z_0$	(B) $\sqrt{2}Z_0$	(C) ∞	(D) 0	
	Where Z ₀ is cha	aracteristic impedance of the	line.		
79.	A 75 Ω transmission line is first short-terminated and the minima locations are noted. When the short is replaced by a resistive load R_L , the minima locations are not altered and the VSWR is measured to be 3. The value of R_L is				
	(A) 25Ω	(B) 50 Ω	(C) 225 Ω	(D) 250Ω	
80.	For a plane wave propagating in an unbounded medium (say, free space), the minimum angle between electric field and magnetic field vectors is				
	(A) 0^0	(B) 60°	(C) 90°	(D) 180°	
81.	Moving-coil permanent magnet instruments can be used for the measurement of				
	(A) AC and DC		(B) AC only		
	(C) DC only		(D) half-wave rectified DC		
82.	For controlling the vibration of the disc of an AC energy meter, damping torque is produced by				
	(A) Eddy current		(B) chemical ef	fect	
	(C) Electrostatic effect		(D) magnetic effect		
83.	Analog inputs are converted to digital outputs using op-amps as comparators.				
	Assuming a 5-bit digital output, the number of comparators required would be				
	(A) 32	(B) 31	(C) 64	(D) 63	
84.	The value of n for the n-bit A/D converter required to convert an analog input in the range o 0 to 5 volts to an accuracy of 10 mV is				
	(A) 8	(B) 9	(C) 7	(D) 6	
85.	One of the following can act as an inverse transducer				
	(A) Electrical resistance potentiometer		(B) LVDT		
	(C) Piezoelectric crystal		(D) Capacitive transducer		
86.	top of the canti	_	d at the bottom. The	ne gauge is mounted on the two strain gauges form two	



(A) a quarter bridge

(B) a half bridge

(C) a full bridge

- (D) a null bridge
- 87. A Hall effect transducer is generally used for the measurement of
 - (A) Power

(B) current

(C) Displacement

- (D) voltage
- 88. A digital linear displacement transducer normally uses
 - (A) Straight binary code

(B) binary coded decimal

(C) Gray code

- (D) hexadecimal code
- 89. The following transducer is used for accurate and precise measurement of temperature
 - (A) Thermistor
 - (b) Thermocouple (Alumel / Chromel)
 - (C) Semiconductor temperature sensor chip
 - (D) Platinum resistance thermometer
- 90. Electrical voltage-based telemetering schemes used for short distances must necessarily have
 - (A) Low current level only
 - (B) small signal power only
 - (C) High signal to noise ratio $\left(\frac{S}{N} >> 2\right)$ only
 - (D) All of the above
- 91. Electrical positional system telemetering uses for transmission of signal in
 - (A) Two wires only
 - (B) Two or three wires only
 - (C) Two or three or four wires only
 - (D) Two or three or four or even five wires



Direction:

Each of the following **nine (9)** items consists of two statements, one labelled as 'Statement (I)' and the other as 'Statement (II)'. You are to examine these two statements carefully and select the answers to these items using code given below:

Code:

- (A) Both Statement (I) and Statement (II) are individually true and Statement (II) is the correct explanation of Statement (I)
- (B) Both Statement (I) and Statement (II) are individually true but Statement (II) is **not** the correct explanation of Statement (I)
- (C) Statement (I) is true but Statement (II) is false
- (D) Statement (I) is false but Statement (II) is true

92. Statement (I):

All substances except ferro-magnetic materials which can form permanent magnets, exhibit magnetic effects.

Statement (II):

Their magnetic effect is due to alignment of dipoles when subjected to an external electromagnetic field.

93. Statement (I):

Concentration of acceptor atoms in the region between isolation islands in a monolithic integrated circuit will be much higher than in the p-type substrate.

Statement (II):

The higher density is provided to prevent the depletion region of the reverse-biased isolation to substrate junction from extending into the p⁺ type material.

94. **Statement (I):**

The gate of MOSFET is insulated from the body of FET by deposition of a very thin fragile layer of SiO₂ over the substrate.

Statement (II):

The device is therefore called as an insulated gate field-effect transistor (IGFET).

95. Statement (I):

Z-transform approach is used to analyze the discrete time systems and is also called as pulse transfer function approach.

Statement (II):

The sampled signal is assumed to be a train of impulses whose strengths, or areas, are equal to the continuous time signal at the sampling instants.



96. Statement (I):

Lossless network functions have only imaginary zeros and poles with only negative real parts.

Statement (II):

Lossless network functions obey the separation property.

97. **Statement (I):**

Resistance hygrometer is a good humidity transducer.

Statement (II):

Resistance hygrometer has a sensing element and absorbs or gives up moisture till equilibrium is reached with ambient water vapour pressure.

98. **Statement (I):**

Dual-slope A/D converter is the most preferred A/D conversion approach in digital multimeters.

Statement (II):

Dual-slope A/D converter provides high accuracy in A/D conversion, while at the same time suppressing the hum effect on the input signal.

99. **Statement (I):**

RF voltage is measured by rectifying the alternating voltage first and then amplifying the resulting DC output.

Statement (II):

Amplification of RF signals is itself a very difficult task.

100. Statement (I):

Digital universal counter timer is used to measure time period and frequency of various circuits which are assembled together to form one complete block.

Statement (II):

Digital counters use logic gates which are selected and controlled by a single front panel switch known as function switch which can be in either frequency or time-base mode.

- 101. Diodes are used to compensate which of the following transistor circuit parameters?
 - $1. I_{CO}$
 - $2. V_{BE}$
 - 3. β
 - (A) 1 and 2 only (B) 2 and 3 only (C) 1 and 3 only (D) 1, 2 and 3



- 102. The relative values of the forward conduction voltage for a *p-n* junction diode, a Red LED and a Schottky barrier diode are
 - (A) Schottky voltage drop > p-n junction diode drop > Red LED drop
 - (B) Red LED drop > p-n junction diode drop > Schottky voltage drop
 - (C) p-n junction diode drop > Schottky voltage drop > Red LED drop
 - (D) Schottky voltage drop > Red LED drop > p-n junction diode drop
- 103. A freewheeling diode in a phase-controlled rectifier
 - (A) improves the line power factor
 - (B) is responsible for additional reactive power
 - (C) Prevents inverse operation
 - (D) is responsible for additional harmonics
- 104. The following equation describes a linear time-varying discrete time system

(A)
$$y(k + 2) + ky(k + 1) + y(k) = u(k)$$

(B)
$$y(k + 2) + ky^2(k + 1) + y(k) = u(k)$$

(C)
$$y(k + 2) + 3y(k + 1) + 2y(k) = u(k)$$

(D)
$$y(k + 2) + y^2(k + 1) + ky(k) = u(k)$$

- 105. Hall effect is useful for the measurement of a semiconductor's
 - (A) Mobility, carrier concentration and temperature
 - (B) Type (n-type or p-type), conductivity and temperature
 - (C) Type (n-type or p-type), mobility and carrier concentration
 - (D) Mobility, conductivity and temperature
- 106. Given:
 - N (E): Density of states
 - F (E): Probability that a quantum state with energy E is occupied by an electron

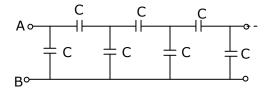
E_C: Energy level of conduction band

The expression
$$\int_{E_C}^{\infty} N(E) f(E) dE$$
 gives

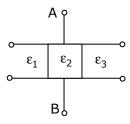
- (A) Minimum number of electrons in conduction band
- (B) Concentration of electrons in conduction band
- (C) Energy of electron concentration in conduction band
- (D) Conductivity of electrons in conduction band



- 107. Non-polar electrolytic capacitors
 - (A) Are used for applications in AC circuits without any DC polarizing voltage
 - (B) Contain two capacitors connected in series with opposing polarities
 - (C) Both (a) and (b) are correct
 - (D) Both (a) and (b) are wrong
- 108. The effective capacitance across AB of the infinite ladder shown in the above figure is



- (A) $\left(1+\sqrt{3}\right)C$ (B) $\left(1+\sqrt{7}\right)C$ (C) $\left(1+\sqrt{5}\right)C$ (D) $\frac{\left(1+\sqrt{5}\right)}{2}C$
- 109. A capacitor of capacitance C is charged by connecting it to a battery of e.m.f. E. The capacitor is now disconnected and reconnected to the battery with the polarity reversed. The heat developed in the connecting wires is
 - (A) 0.5 CE^2
- (B) CE^2
- (C) 2 CE^2
- (D) 3 CE^2
- 110. The space between the plates of a parallel-plate capacitor of capacitance C is filled with three dielectric slabs of identical size as shown in the figure. If dielectric constants are $\varepsilon_1, \varepsilon_2$ and ε_3 the new capacitance is



(A) $\frac{C}{3}$

(B) $\frac{(\varepsilon_1 + \varepsilon_2 + \varepsilon_3)C}{3}$

(C) $(\varepsilon_1 + \varepsilon_2 + \varepsilon_3)$ C

(D) $\frac{9(\varepsilon_1 + \varepsilon_2 + \varepsilon_3)}{\varepsilon_1 \varepsilon_2 \varepsilon_3}$

111.	Superconductors are becoming popular for their use in				
	(A) Generating very strong magnetic field				
	(B) Manufacture of bubble memories				
	(C) Generating electr	rostatic field			
	(D) Generating region	ons free from magnetic fie	ld		
112.	An ideal low-pass filter has a cutoff frequency of 100 Hz. If the input to the filter in volts is $v(t) = 30\sqrt{2} \sin 1256t$, the magnitude of the output of the filter will be				
	(A) 0 V	(B) 20 V	(C) 100 V	(D) 200 V	
113.	A bar magnet made of steel has a magnetic moment of 2.5 A-m2 and a mass of 6.6 x 10^3 kg. If the density of steel is 7.9×10^3 kg/m ³ , the intensity of magnetization is				
	(A) $8.3 \times 10^{-7} \text{A/m}$		(B) $3x10^6$ A/m		
	(C) $6.3x10^{-7}$ A/m		(D) $8.2x10^6$ A/m		
114.	If the drift velocity of holes under a field gradient of 200 V/m is 100 m/s, their mobility is SI units is				
	(A) 0.5	(B) 0.05	(C) 50	(D) 500	
115.	A flux of 1.2 mWb exerts in a magnet having a cross-section of 30 cm ² . The flux density in tesla is				
	(A) 4	(B) 0.4	(C) 2.5	(D) 40	
116.	In a transconductanc	e, the device output			
	(A) Voltage depends upon the input voltage (B) Voltage depends upon the input current				
	(C) Current depends	upon the input voltage	(D) Current depends	s upon the input current	
117.	A potential barrier of 0.50 V exists across a p - n junction. If the depletion region is 5.0×10^{-7} m wide, what is the intensity of the electric field in this region?				
	(A) $1.0x10^6$ V/m	(B) $2.5x10^{-7}$ V/m	(C) $2.5 \times 10^{-7} \text{V/m}$	(D) $2.5 \times 10^8 \text{V/m}$	
118.	meter. Antimony is of half of the impurity the number of charge meter is 5×10^{28}) is	Thole-electron pairs in pur loped into silicon in a pro- atoms contribute electron e carries increases due to	oportion of 1 atom to 10 as in the conduction ba	O ⁷ atoms. Assuming that and, the factor by which	
	(A) $14x10^{15}$	(B) $0.5x10^{21}$	(C) 2.5×10^{21}	(D) 1.8×10^5	



- 119. A piece of writing paper that is 10 cm wide, 15 cm long and 0.05 mm thick has a dielectric strength of 8 kV/mm. If it is placed between two copper plates and subjected to an increasing voltage, it will break down at
 - (A) 8 kV
- (B) 4 kV
- (C) 0.4 kV
- (D) 0.8 kV
- 120. Match List-I with List-II and select the correct answer using the code given below the

List - I	List – II
P. Electrostriction	1. Converse of Seebeck effect
Q. Ionic conductivity	2. Reverse effect of piezoelectricity
R. Peltier heat	3. Converse effect of magnetostriction
S. Villari effect	4. Conductivity of insulators

Codes:

P Q R S

- (A) 2 4 1 3
- (B) 2 1 4 3
- (C) 3 4 1 2
- (D) 3 1 4 2